

Bonding analysis of telluroketones $H_2A=Te$ ($A = C, Si, Ge$)

Naziah B. Jaufeerally · Ponnadurai Ramasami ·
Paul Jerabek · Gernot Frenking

Received: 27 February 2014 / Accepted: 25 August 2014 / Published online: 21 September 2014
© Springer-Verlag Berlin Heidelberg 2014

Abstract Quantum chemical calculations using density functional theory BP86/def2-TZVPP and ab initio methods at CCSD(T)/def2-TZVPP have been carried for the telluroketones $H_2A=Te$ ($A = C, Si, Ge$). DFT calculations have also been carried out for the ketones $H_2C=E$ ($E = O, S, Se, Te$) and for the complexes $NHC \rightarrow [H_2A=Te] \rightarrow B(C_6F_5)_3$. The nature of the bonding has been investigated with charge- and energy decomposition analyses. The calculated bond dissociation energies for the double bonds of the $H_2C=E$ and $H_2A=Te$ molecules show the expected trends $O > S > Se > Te$ for atom E and $C > Si > Ge$ for atom A. Complexation of the telluroketones in $NHC \rightarrow [H_2A=Te] \rightarrow B(C_6F_5)_3$ leads to longer and weaker A-Te bonds which exhibit the surprising trend for the bond dissociation energy $Si > Ge > C$. The contribution of the π bonding in $H_2A=Te$ increases for the heavier atoms with the sequence $C < Si < Ge$.

Keywords Telluroketones · Molecular orbitals · Natural bond orbital · Energy decomposition analysis

Introduction

Carbonyl ($C=O$) and thiocarbonyls compounds ($C=S$) are ubiquitous building blocks in nature and have been explored for their uses from the chemical industry to bioscience [1].

This paper belongs to a Topical Collection on the occasion of Prof. Tim Clark's 65th birthday

Electronic supplementary material The online version of this article (doi:10.1007/s00894-014-2433-z) contains supplementary material, which is available to authorized users.

N. B. Jaufeerally · P. Ramasami (✉)
Computational Chemistry Group, Department of Chemistry,
University of Mauritius, Réduit, Mauritius
e-mail: ramchemi@intnet.mu

P. Jerabek · G. Frenking (✉)
Fachbereich Chemie, Philipps-Universität Marburg, 35032 Marburg,
Germany
e-mail: frenking@chemie.uni-marburg.de

P. Jerabek
e-mail: paul.jerabek@chemie.uni-marburg.de

Selenocarbonyls ($C=Se$) have also been of great interest since selenium-containing fragments can be introduced readily into an organic compound and, after appropriate transformations, the selenium atom can be removed easily by simple processes [2]. Besides, the redox catalytic activity of selenium-containing peptides is found to be switchable, leading to the development of nature-mimicking smart materials with promising properties [3].

The importance of $C=O$, $C=S$ and $C=Se$ moieties has prompted numerous chemists to synthesize stable heavier-element congeners with double bonds between heavier group 14 and group 16 elements $R_2A=E$ ($A = Si, Ge, Sn, Pb$; $E = S, Se, Te$), known as “heavy ketones”. The considerable progress being made in the chemistry of compounds with multiple bonds with heavier group 14 elements is not merely because of experimental curiosity but also because such compounds are capable of activating small molecules and thus mimic transition elements [4, 5]. However, telluro-ketones have received scant importance compared to oxo-, thio- and seleno-analogues, yet stable and isolable $Si=Te$ [6] and $Ge=Te$ [7] compounds have already been synthesized. Recently, Tiekink reported that compounds with $C-Te$ bonds offer possibilities as therapeutic agents, and their biological functions deserve more attention [8]. Therefore, it is important to gather accurate data for organotellurium compounds.

Attempts to synthesize and isolate heavy ketones have met with great difficulties due to the polarity of both the σ and π bonds of $A=E$, which contribute to the spontaneous intermolecular oligomerization or polymerization of the heavy ketones [9–14]. Based on the kinetic stabilization concept, some stable heavy ketones with various combinations between heavier group 14/16 elements $R_2A=E$ have been synthesized and isolated using bulky substituents R [15–21]. Recently, with the first successful isolation of a germanone ($Eind$)₂Ge=O ($Eind = 1,1,3,3,5,5,7,7$ -octaethyl-s-hydrindacen-4-yl), Li et al. [22] reported that the isomerization process can be inhibited by rigid bulky protecting groups. All these isolatable heavy ketones bear sterically encumbered substituents from group 14 elements while the group 16

elements are left unsupported. Very recently, Ghadwal et al. [23] exploited the stabilization of $R_2A=E$ with N-heterocyclic carbenes (NHCs) and reported the first Lewis donor-acceptor stabilized silacarbonyl halide, $NHC^1 \rightarrow [SiH(Cl)=O] \rightarrow B(C_6F_5)_3$ ($NHC^1 = 1,3\text{-bis}(2,6\text{-diisopropyl-phenyl})\text{imidazol-2-ylidene}$), in which the oxygen atom is also protected.

Telluroformaldehyde ($H_2C=Te$), was first stabilized by coordination to transition-metal centers by Roper et al. in 1983 [24, 25]. The first stable germanetellones, $Tbt(Dis)Ge=Te$ and $Tbt(Tip)Ge=Te$ ($Tbt = 2,4,6\text{-tris}[\text{bis}(\text{trimethylsilyl})\text{methyl}]\text{phenyl}$, $Dis = \text{bis}(\text{trimethylsilyl})\text{methyl}$ and $Tip = 2,4,6\text{-triisopropylphenyl}$) were reported in 1997 [15–21]. A free telluroketone $R_2C=Te$, where R_2 is cyclic 1,1,3,3-tetramethylindane, has been synthesized in solution but the structure could not be determined by X-ray analysis [26]. The synthesis and isolation of free telluroketones bearing the $Si=Te$ and $Ge=Te$ moieties remains elusive. Recently, we reported the structures and energetics of $R_2A=Te$ and $R^1R^2A=Te$ ($A = C$ and Si and $R = H, F, Cl, Br, I$ and CN) molecules [27, 28]. In this work, we analyze the nature of the bonding in the telluroketones $H_2A=Te$ and $NHC \rightarrow H_2A=Te \rightarrow B(C_6F_5)_3$ ($A = C, Si, Ge$) complexes with donor-acceptor ligands. The parent ketones $H_2C=E$ ($E = O, S$ and Se) were also investigated for comparison purposes.

Methods

The ketones and complexes were optimized using the BP86 functional [29, 30] using Gaussian 03 [31] in conjunction with the Turbomole 6.3 [32] program package. The RI approximation [33] was applied using auxiliary basis functions [34–36]. The Ahlrichs def2-TVZPP basis sets [37] were used for all the atoms. An effective core potential [38] was used for the tellurium atom. Stationary points were characterized by calculating the Hessian matrix analytically. Frequencies and thermodynamics corrections were calculated with the aoforce [39–41] program of the Turbomole package. The telluroketones were also optimized at the CCSD(T) level [42] with cc-pVTZ basis sets [43–46] using MOLPRO [47]. Atomic partial charges were calculated using the natural bond orbital (NBO) method [48, 49]. The functional BP86 was chosen because numerous studies by our group in the past have shown that it gives quite accurate geometries and energies [50–53].

Energy decomposition analyses (EDA) [54] were carried out using the ADF (2012.02) program package at the BP86/TZ2P+ level of theory [55]. Uncontracted Slater-type orbitals (STOs) were employed as basis functions in self-consistent field (SCF) calculations [56]. Triple-zeta-quality basis sets were used, which were augmented by two sets of polarization functions, i.e., p and d functions for the hydrogen

atom and d and f functions for the other atoms. An auxiliary set of s, p, d, f and g STOs was used to fit the molecule densities and to represent the Coulomb and exchange potentials accurately in each SCF cycle [57]. Scalar relativistic effects were considered using the zero-order regular approximation (ZORA) [58–62].

Within the EDA, bond formation between the interacting fragments is divided into three steps: in the first step, fragments calculated with the frozen geometry of the entire molecule were superimposed without electronic relaxation to yield the quasiclassical electrostatic attraction ΔE_{elstat} . In the second step, the product wave function becomes antisymmetrized and renormalized, which gave the repulsive term ΔE_{Pauli} , named Pauli repulsion. The third step consists of relaxation of the molecular orbitals to their final form to yield the stabilizing orbital interaction ΔE_{orb} . The sum of the three terms $\Delta E_{\text{elstat}} + \Delta E_{\text{Pauli}} + \Delta E_{\text{orb}}$ gives the total interaction energy ΔE_{int} . The orbital interactions ΔE_{orb} can be divided into pairwise contributions of the interacting fragments with the extended EDA-natural orbitals for chemical valence (NOCV) method [63]. Further details and examples of EDA and EDA-NOCV calculations are available from the literature [64–68].

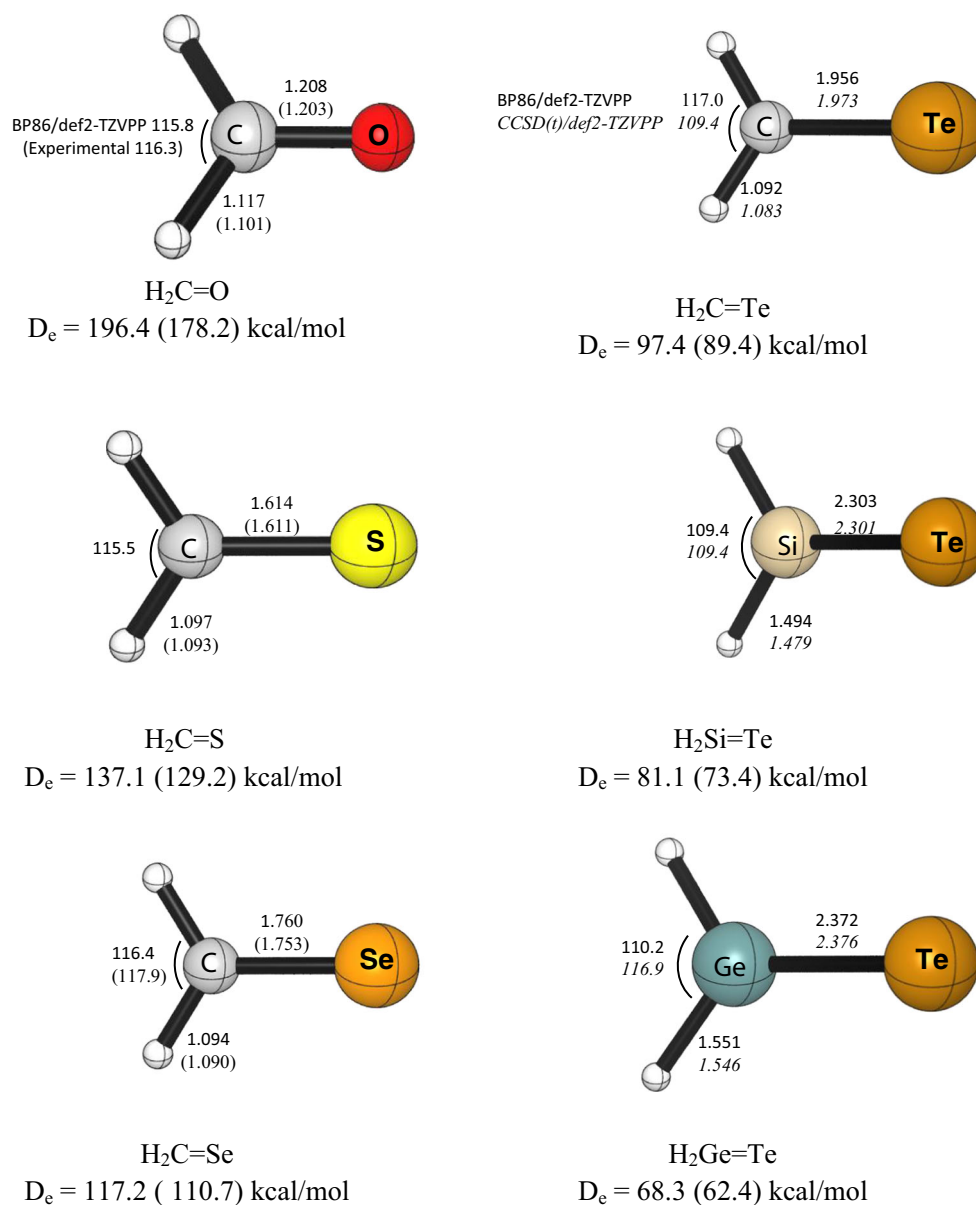
Results and discussion

Geometries and energies

Figure 1 shows the calculated BP86/def2-TZVPP geometries for $H_2C=E$ ($E = O, S, Se$) alongside the experimentally known bond lengths and bond angles. The agreement of the experimental values with the calculated data was very good. No experimental data are available for $H_2C=Te$. We calculated the geometry of the telluroketones $H_2A=Te$ at the BP86/def2-TZVPP and CCSD(T)/def2-TZVPP levels of theory. The agreement between the two levels of theory was reasonable. The H–E–H angle at CCSD(T)/def2-TZVPP is more acute for $E = C$ but it is wider for $E = Ge$ compared with the BP86/def2-TZVPP values, while the A–Te distances agree quite well. The calculated bond dissociation energies (BDEs) for the $H_2C=E$ and $H_2A=Te$ bonds at CCSD(T)/def2-TZVPP and BP86/def2-TZVPP show the expected trends for $D_e = O > S > Se > Te$ for atom E and $C > Si > Ge$ for atom A. The latter values are a bit higher than the former but the differences are not relevant for this work. The calculated D_e values are in good agreement with previous high-level calculations [69].

Figure 2 shows the theoretically predicted equilibrium geometries of the complexes $NHC \rightarrow [H_2A=Te] \rightarrow B(C_6F_5)_3$ ($A = C, Si, Ge$), which possess an antiperiplanar arrangement

Fig. 1 Calculated geometries of $H_2A=E$. Bond dissociation energies (D_e) at BP86/def2-TZVPP and at CCSD(T)/cc-pVTZ (in parentheses). Bond lengths are in Ångstroms and angles are in degrees. References for experimental data: $H_2C=O$ [75]; $H_2C=S$ [76]; $H_2C=Se$ [77]

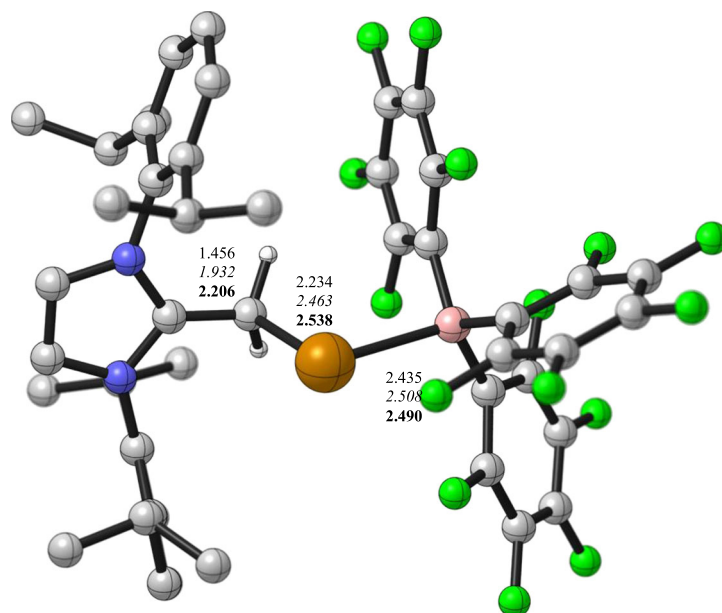


of the donor and acceptor moieties. The torsion angle C–A–Te–B for all complexes is 180° . The comparison with the free telluroketones makes it obvious that the A–Te bonds become significantly longer between 0.27 \AA (A = C) and 0.16 \AA (A = Si, Ge) [70, 71]¹. The same trend is also calculated for the BDEs of the A–Te bonds in the complexes, which are clearly weaker than in the free compounds. Note that the theoretically predicted A–Te bond strength in the complexes $NHC \rightarrow$

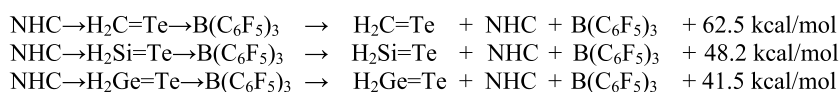
¹ The calculated bond length and the bonding analysis indicates that the A–Te bonds in the complexes are single bonds. We keep the formal notation with double bonds $NHC \rightarrow [H_2A=Te] \rightarrow B(C_6F_5)_3$, which sketches the bonding situation between the isolated fragments. For a discussion of using arrows for chemical bonds.

$[H_2A=Te] \rightarrow B(C_6F_5)_3$ has the trend $Si > Ge > C$, which is clearly different than for free $H_2A=Te$. The calculations predict that the carbon complex $NHC \rightarrow [H_2C=Te] \rightarrow B(C_6F_5)_3$ has the weakest bond to Te and that the silicon species $NHC \rightarrow [H_2Si=Te] \rightarrow B(C_6F_5)_3$ has the strongest bond. The peculiar bond weakening of the A–E bonds may be related to the strength of the donor-acceptor interactions in the complexes. Figure 2 shows that the complexation energies for the reaction $NHC \rightarrow [H_2A=Te] \rightarrow B(C_6F_5)_3 \rightarrow H_2A=Te + NHC + B(C_6F_5)_3$, which exhibit the trend $C > Si > Ge$, are rather high. The very large strong donor-acceptor interactions of the carbon complex apparently weakens the C–Te bond to such an extent that it becomes weaker than the other two A–Te bonds.

Fig. 2 Calculated geometries (BP86/def2-TZVPP) of the complexes $\text{NHC} \rightarrow [\text{H}_2\text{E}=\text{Te}] \rightarrow \text{B}(\text{C}_6\text{F}_5)_3$ ($\text{E} = \text{C}, \text{Si}, \text{Ge}$) and bond dissociation energies D_e . Bond lengths are in Ångstroms and angles are in degrees



$$\begin{aligned} D_e(\text{C-Te}) &= 41.0 \text{ kcal/mol} \\ D_e(\text{Si-Te}) &= 63.3 \text{ kcal/mol} \\ D_e(\text{Ge-Te}) &= 53.9 \text{ kcal/mol} \end{aligned}$$



Bonding analysis

Inspection of the molecular orbitals of the telluroketones $\text{H}_2\text{A}=\text{Te}$ shows that the highest occupied molecular orbital (HOMO) is the $\text{A}=\text{Te}$ π orbital while the lowest unoccupied molecular orbital (LUMO) is the $\text{A}=\text{Te}$ π^* orbital (Fig. 3). The NBO analysis is in agreement with the expected Lewis picture of the $\text{A}-\text{Te}$ bonds, i.e., there is a σ and a π bond (Table 1). According to the NBO results, the $\text{C}-\text{Te}$ σ bond is clearly polarized toward the carbon end, while the π bond is nearly unpolar. The $\text{Si}-\text{Te}$ and $\text{Ge}-\text{Te}$ σ bonds are nearly unpolar but the π bonds are polarized towards Te. This leads to a positive partial charge at Te in $\text{H}_2\text{C}=\text{Te}$ while the tellurium atoms in $\text{H}_2\text{A}=\text{Te}$ ($\text{A} = \text{Si}, \text{Ge}$) carry a negative charge (Table 1).

The antiperiplanar arrangement of the donor and acceptor fragments in $\text{NHC} \rightarrow [\text{H}_2\text{A}=\text{Te}] \rightarrow \text{B}(\text{C}_6\text{F}_5)_3$ indicate that the donation $\text{NHC} \rightarrow \text{H}_2\text{A}=\text{Te}$ takes place into the vacant $\text{A}=\text{Te}$ π^* orbital while the $\text{Te} \rightarrow \text{B}(\text{C}_6\text{F}_5)_3$ donation occurs through the occupied $\text{A}=\text{Te}$ π MO. This is in agreement with the NBO analysis of the complexes $\text{NHC} \rightarrow [\text{H}_2\text{A}=\text{Te}] \rightarrow \text{B}(\text{C}_6\text{F}_5)_3$, which show that there is no occupied $\text{A}=\text{Te}$ π orbital (Table 2). Thus, the bonding situation in the complexes should be described either in terms of donor-acceptor bonds $\text{NHC} \rightarrow \text{H}_2\text{A}=\text{Te} \rightarrow \text{B}(\text{C}_6\text{F}_5)_3$ or, alternatively, as zwitterion $\text{NHC}^+ - \text{H}_2\text{A}=\text{Te}^- - \text{B}(\text{C}_6\text{F}_5)_3$. This is in agreement with the calculated

partial charges, which indicate that the fragments $\text{TeB}(\text{C}_6\text{F}_5)_3$ and $\text{B}(\text{C}_6\text{F}_5)_3$ are acceptor moieties (Table 2). The NBO results

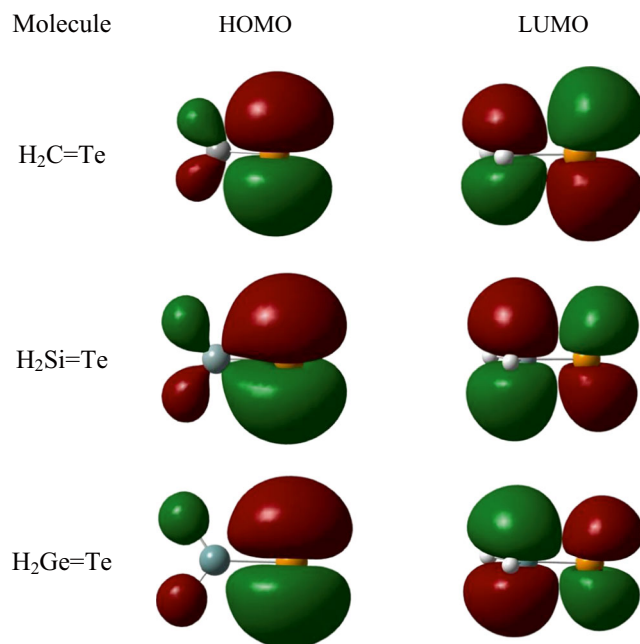


Fig. 3 Shape of the highest occupied molecular orbital (HOMO) and lowest unoccupied molecular orbital (LUMO) of $\text{H}_2\text{A}=\text{Te}$

Table 1 Natural bond orbital (NBO) partial charges (q) and results of the relevant occupied orbitals of $H_2A=Te$ ($A = C, Si, Ge$) at BP86/def2-TZVPP

Orbital	Occupation	Contributions of atom to the orbital (%)	Composition %		$q(Te)$
			s	p	
$H_2C=Te$					
					+0.26
BD(1) C–Te (σ)	1.998	C: 61.8 Te: 38.2	34.2 13.4	65.8 86.4	
BD(1) C–Te (π)	1.999	C: 48.8 Te: 51.2	0.0 0.0	99.8 99.7	
LP(1) Te (σ)	1.995		87.8	12.2	
LP(2) Te (π)	1.952		0.0	100.0	
$H_2Si=Te$					
					-0.24
BD(2) Si–Te (σ)	1.976	Si: 47.5 Te: 52.5	37.0 12.6	62.6 87.2	
BD(1) Si–Te (π)	1.999	Si: 32.4 Te: 67.6	0.0 0.0	98.9 99.7	
LP(1) Te (σ)	1.988		87.6	12.4	
LP(2) Te (π)	1.859		0.0	99.9	
$H_2Ge=Te$					
					-0.23
BD(2) Ge–Te (σ)	1.898	Ge: 49.9 Te: 50.2	37.0 10.4	62.8 89.1	
BD(1) Ge–Te (π)	1.999	Ge: 32.2 Te: 67.8	0.0 0.0	99.3 99.7	
LP(1) Te (σ)	1.984		89.7	10.4	
LP(2) Te (π)	1.891		0.0	99.9	

suggest that Te has two electron lone pairs and that the polarity of the A–Te σ bond changes only slightly in the complexes.

Table 3 shows the results of the EDA calculations of the systems $H_2A=E$. The intrinsic C=E bond strength of the carbon systems $H_2C=E$, which is given by the interaction energy ΔE_{int} between the frozen fragments H_2C and E in the triplet state, decreases in the expected order $O > S > Se > Te$. The C=E bonds are more covalent than electrostatic in character but the degree of covalence, which is given by the percentage contribution of ΔE_{orb} to the total attraction, decreases also with the same trend $O > S > Se > Te$. Note that the π contribution of $\Delta E(b_1)\pi_{\perp}$ to the orbital term remains nearly the same for the chalcogen atoms. It has been shown before that the alleged weakening of π bonds of heavier main group atoms, which is sometimes stated to be the reason for the lower stability of molecules that have multiple bonds between main group elements is a myth [72–74]. The calculated trend of the bond dissociation energies, D_e , is very similar to the ΔE_{int} values, which agrees quite well with previous results

Table 2 NBO partial charges (q) and results of the relevant occupied orbitals of $NHC \rightarrow [H_2A=Te] \rightarrow B(C_6F_5)_3$ ($A = C, Si, Ge$) at BP86/def2-TZVPP

Orbital	Occupation	Contributions of atom to the orbital (%)	Composition %		q	q
			s	p		
$NHC \rightarrow [H_2C=Te] \rightarrow B(C_6F_5)_3$						
					+0.21	-1.06
BD(1) C–Te (σ)	1.889	C: 65.3 Te: 34.8	18.6 6.6	81.3 93.2		
LP(1) Te (σ)	1.980		81.1	18.9		
LP(2) Te (π)	1.914		0.1	99.9		
$NHC \rightarrow [H_2Si=Te] \rightarrow B(C_6F_5)_3$						
					-0.10	-1.30
BD(2) Si–Te (σ)	1.946	Si: 48.3 Te: 51.7	22.6 10.0	71.7 89.9		
LP(1) Te (σ)	1.967		78.1	21.9		
LP(2) Te (π)	1.844		0.1	99.9		
$NHC \rightarrow [H_2Ge=Te] \rightarrow B(C_6F_5)_3$						
					-0.07	-0.26
BD(2) Ge–Te (σ)	1.934	Ge: 50.8 Te: 49.2	28.3 8.0	71.6 81.7		
LP(1) Te (σ)	1.967		79.8	20.2		
LP(2) Te (π)	1.870		0.1	99.9		

[69]. This is because the rather small preparation energies ΔE_{prep} do not change very much along the series.

The strength of the interaction energies ΔE_{int} for the telluroketones $H_2A=Te$ decreases in the order $C > Si > Te$ but the differences are not very large. In contrast, the D_e values have a much larger slope with decreasing values for D_e (Table 3). This is because the preparation energies of the heavier systems become significantly larger. The ΔE_{prep} values of H_2Si and H_2Ge include the electronic excitation energy from the singlet ground state to the triplet excited state, which is the reference state for $H_2Si=Te$ and $H_2Ge=Te$. We want to draw attention to the increase in π bonding in the series $H_2A=Te$ when A becomes bigger. Table 3 shows that the percentage contribution of $\Delta E(b_1)\pi_{\perp}$ to ΔE_{orb} in $H_2A=Te$ becomes larger with the trend $C < Si < Te$. This is in agreement with analysis of the bonding in E_2 ($E = N - Bi$) which shows that the relative contribution of π bonding in the heavier species P_2 and As_2 is bigger than in N_2 [73].

We also analyzed the A–Te bonds in the complexes $NH \rightarrow [H_2A=Te] \rightarrow B(C_6F_5)_3$ with the EDA method in order to investigate the change in bonds between the free molecules $H_2A=Te$ and the complexes. Table 4 shows the results of the EDA-NOCV calculations. The EDA-NOCV makes it possible to separate the specific contributions of the σ - and

Table 3 Energy decomposition analyses (EDA) calculations of the compounds $H_2A=E$ ($A = C, Si, Ge$; $E = O, Si, Se, Te$) at BP86/def2-TVZPP. The interacting fragments are AH_2 and E in the electronic triplet states. Energy values are in $kcal\ mol^{-1}$

	$H_2C=O$	$H_2C=S$	$H_2C=Se$	$H_2C=Te$	$H_2Si=Te$	$H_2Ge=Te$
ΔE_{int}	-196.6	-141.3	-122.2	-103.1	-100.7	-94.5
ΔE_{Pauli}	488.3	290.8	247.2	205.2	168.2	153.9
ΔE_{elstat}	-199.5 (29.1 %)	-166.1 (38.4 %)	-155.8 (42.2 %)	-139.0 (45.1 %)	-119.8 (44.6 %)	-110.2 (44.4 %)
ΔE_{orb}	-485.4 (70.9 %)	-266.0 (61.6 %)	-213.6 (57.8 %)	-169.3 (54.9 %)	-149.1 (55.4 %)	-138.2 (55.6 %)
$\Delta E(a_1)\sigma^b$	-348.4 (71.8 %)	-190.9 (71.8 %)	-156.6 (73.3 %)	-127.6 (75.4 %)	-94.6 (63.4 %)	-90.2 (65.3 %)
$\Delta E(a_2)\delta^b$	0	0	0	0	0	0
$\Delta E(b_1)\pi_{\perp}^b$	-109.5 (22.6 %)	-61.0 (22.9 %)	-47.4 (22.2 %)	-34.9 (20.6 %)	-41.4 (27.7 %)	-38.9 (28.1 %)
$\Delta E(b_2)\pi_{\parallel}^b$	-27.5 (5.7 %)	-14.1 (5.3 %)	-9.7 (4.5 %)	-6.7 (4.0 %)	-13.1 (8.8 %)	-9.1 (6.6 %)
ΔE_{prep}	0.2	4.2	5.0	5.7	19.6	26.2
D_e	196.4 (181.4) ^c	137.1 (133.8) ^c	117.2 (114.0) ^c	97.4	81.1	68.3

^a Values in parentheses give the percentage contribution to the total attractive interactions $\Delta E_{elstat} + \Delta E_{orb}$

^b Values in parentheses give the percentage contribution to the total orbital interactions ΔE_{orb}

^c Ref. [69]

π bonding, which come from the pairwise interactions between the fragments $NHC(H_2A)$ and $TeB(C_6F_5)_3$. The calculated data show that the much lower BDE of the carbon species $NHC \rightarrow [H_2C=Te] \rightarrow B(C_6F_5)_3$ comes from weakening of the C–Te interaction energy. The ΔE_{int} value in the complex is much smaller ($-79.3\ kcal\ mol^{-1}$) than in free $H_2C=Te$ ($-103.1\ kcal\ mol^{-1}$, Table 3). Inspection of the energy terms of the EDA-NOCV calculations suggests that the weakening is mainly due to the loss of π bonding in $NHC \rightarrow [H_2C=Te] \rightarrow B(C_6F_5)_3$, which contributes only $-9.6\ kcal\ mol^{-1}$ to ΔE_{orb} (Table 4) while it is $-34.9\ kcal\ mol^{-1}$ in free $H_2C=Te$. A surprising result comes from the EDA-NOCV data for the

Table 4 EDA-natural orbitals for chemical valence (NOCV) calculations (BP86/TZ2P+) of the A–Te bonds in the complexes $NHC \rightarrow [H_2A=Te] \rightarrow B(C_6F_5)_3$ using the fragments: $NHC(H_2A)$ and $TeB(C_6F_5)_3$ in the singlet state. The energy values are in $kcal\ mol^{-1}$

$NHC \rightarrow [H_2A=Te] \rightarrow B(C_6F_5)_3$			
	A = C	A = Si	A = Ge
ΔE_{int}	-79.3	-99.4	-90.4
ΔE_{Pauli}	195.0	256.4	219.5
ΔE_{elstat}^a	-130.9 (47.6 %)	-170.1 (47.8 %)	-147.6 (47.6 %)
ΔE_{orb}^a	-144.0 (52.4 %)	-185.7 (52.2 %)	-162.3 (52.4 %)
$\Delta E_{orb}(\sigma)^b$	-122.0 (84.7 %)	-159.0 (85.6 %)	-142.3 (87.6 %)
$\Delta E_{orb}(\pi)^b$	-9.6 (6.7 %)	-11.6 (6.2 %)	-8.8 (5.4 %)
$\Delta E_{orb, rest}^b$	-12.4 (8.6 %)	-15.1 (8.1 %)	-11.2 (6.9 %)
ΔE_{prep}	38.3	36.1	36.5
D_e	41.0	63.3	53.9

^a Values in parentheses give the percentage contribution to the total attractive interactions $\Delta E_{elstat} + \Delta E_{orb}$

^b Values in parentheses gives the percentage contribution to the total orbital interactions ΔE_{orb}

silicon system $NHC \rightarrow [H_2Si=Te] \rightarrow B(C_6F_5)_3$. The data in Table 4 show that the intrinsic interaction ΔE_{int} in the complex is not much weaker ($-99.4\ kcal\ mol^{-1}$) than in free $H_2Si=Te$ ($-100.7\ kcal\ mol^{-1}$, Table 3). Inspection of the energy terms in $NHC \rightarrow [H_2Si=Te] \rightarrow B(C_6F_5)_3$ reveals that the Si–Te σ orbital interactions in the complex ($-159.0\ kcal\ mol^{-1}$) are stronger than the total orbital interactions in the Si=Te double bond of free $H_2Si=Te$ ($-149.1\ kcal\ mol^{-1}$, Table 3). A similar situation is found for the Ge–Te bonds in $NHC \rightarrow [H_2Ge=Te] \rightarrow B(C_6F_5)_3$ and $H_2Ge=Te$. The Ge–Te σ orbital interactions in the complex ($-142.3\ kcal\ mol^{-1}$) are stronger than the total orbital interactions in the Ge=Te double bond of free $H_2Ge=Te$ ($-138.2\ kcal\ mol^{-1}$, Table 3). The smaller BDEs for the A–Te bonds in the latter two complexes compared with the free species $H_2A=Te$ ($A = Si, Ge$) comes from the bigger preparation energies ΔE_{prep} in the adducts.

Summary and conclusions

The results of this work can be summarized as follows. The calculated bond dissociation energies for the $H_2C=E$ and $H_2A=Te$ show the expected trends $O > S > Se > Te$ for atom E and $C > Si > Ge$ for atom A. Complexation of the telluroketones in $NHC \rightarrow [H_2A \rightarrow Te] \rightarrow B(C_6F_5)_3$ leads to longer and weaker A–Te bonds, which exhibit a surprising trend for the bond dissociation energy of $Si > Ge > C$. The contribution of the π bonding in $H_2A=Te$ increases for the heavier atoms with the sequence $C < Si < Ge$.

Acknowledgments N.J. and P.R. acknowledge the facilities offered by the University of Mauritius and the Tertiary Education Commission of Mauritius. P.R. is also grateful to the financial support from German academic exchange service (DAAD). P.J. and G.F. acknowledge financial support by the Deutsche Forschungsgemeinschaft.

References

- Vollhardt KPC (2011) Organic chemistry: structure and function. Freeman, New York
- Potapov VA, Amosova SV (2003) Russ J Org Chem 39:1373
- Miao X, Cao W, Zheng W, Wang J, Zhang X, Gao J, Yang C, Kong D, Xu H, Wang L, Yang Z (2013) Angew Chem Int Ed Engl 52:7781
- Fischer RC, Power PP (2010) Chem Rev 110:3877
- Power PP (2010) Nature 463:171
- Yao S, Xiong Y, Brym M, Driess M (2008) Chem Asian J 3:113
- Tokitoh N, Matsumoto T, Okazaki R (1997) J Am Chem Soc 119:2337
- Tiekink ERT (2012) Dalton Trans 41:6390
- Kapp J, Remko M, Schleyer PvR (1996) J Am Chem Soc 118: 5751
- Takeda N, Tokitoh N, Okazaki R (2000) Chem Lett 3:244
- Iwamoto T, Masuda H, Ishida S, Kabuto C, Kira M (2004) J Organomet Chem 689:1337
- Ibrahim Al-Rafia S M, Lummis PA, Ferguson MJ, McDonald R, Rivard E (2010) Inorg Chem 49:9709
- Mandal SK, Roesky HW (2010) Chem Commun 46:6016
- Asay M, Jones C, Driess M (2011) Chem Rev 111:354
- Tokitoh N, Matsumoto T, Manmaru K, Okazaki R (1993) J Am Chem Soc 115:8855
- Suzuki H, Tokitoh N, Nagase S, Okazaki R (1994) J Am Chem Soc 116:11578
- Saito M, Tokitoh N, Okazaki R (1997) J Am Chem Soc 119:11124
- Tokitoh N, Matsumoto T, Okazaki R (1997) J Am Chem Soc 119:2337
- Suzuki H, Tokitoh N, Okazaki R, Nagase S, Goto M (1998) J Am Chem Soc 120:11096
- Matsumoto T, Tokitoh N, Okazaki R (1999) J Am Chem Soc 121:8811
- Iwamoto T, Sato K, Ishida S, Kabuto C, Kira M (2006) J Am Chem Soc 128:16914
- Li L, Fukawa T, Matsuo T, Hashizume D, Fueno H, Tanaka K, Tamao K (2012) Nature Chem 4:361
- Ghadwal RS, Azhakar R, Roesky HW, Pröpper K, Dittrich B, Goedecke C, Frenking G (2012) Chem Commun 48:8186
- Roper WR, Headford CEL (1983) J Organomet Chem 244:C53
- Roper WR, Hill AF, Waters JM, Wright AH (1983) J Am Chem Soc 105:5939
- Minoura M, Kawashima T, Okazaki R (1993) J Am Chem Soc 115:7019
- Jauferally NB, Abdallah HH, Ramasami P, Schaefer III HF (2012) Theor Chem Acc 131:1127
- Jauferally NB, Abdallah HH, Ramasami P (2013) Comp Theor Chem 1016:62
- Becke AD (1988) Phys Rev A 38:3098
- Perdew JP (1986) Phys Rev B 33:8822
- Gaussian 03, Revision E.01, Frisch MJ, Trucks GW, Schlegel HB, Scuseria GE, Robb MA, Cheeseman JR, Montgomery Jr JA, Vreven T, Kudin KN, Burant JC, Milliam JM, Iyengar SS, Tomasi J, Barone V, Mennucci B, Cossi M, Scalmani G, Rega, N.; Petersson GA, Nakatsuji H, Hada M, Ehara M, Toyota K, Fukuda R, Hasegawa J, Ishida M, Nakajima T, Honda Y, Kitao O, Nakai H, Klene M, Li X, Knox JE, Hratchian HP, Cross JB, Adamo C, Jaramillo J, Gomperts R, Stratmann RE, Yazyev O, Austin AJ, Cammi R, Pomelli C, Ochterski JW, Ayala PY, Morokuma K, Voth GA, Salvador P, Dannenberg JJ, Zakrzewski VG, Dapprich S, Daniels AD, Strain MC, Farkas O, Malick DK, Rabuck, AD, Raghavachari K, Foresman JB, Ortiz JV, Cui Q, Baboul AG, Clifford S, Cioslowski J, Stefanov BB, Liu G, Liashenko A, Piskorz P, Komaromi I, Martin RL, Fox D J, Keith T, Al-Laham MA, Peng CY, Nanayakkara A, Challacombe M, Gill PMW, Johnson B, Chen W, Wong C, Gonzalez MW, Pople JA (2004) Gaussian Inc, Pittsburgh PA
- Ahlrichs R, Bär M, Häser M, Horn H, Kölmel C (1989) Chem Phys Lett 162:165
- Ahlrichs R (2004) Phys Chem Chem Phys 6:5119
- Eichkom K, Treutler O, Öhm H, Häser M, Ahlrichs R (1995) Chem Phys 242:652
- Eichkom K, Weigend F, Treutler O, Ahlrichs R (1997) Theor Chem Acc 97:119
- Weigend F (2006) Phys Chem Chem Phys 8:1057
- Weigend F, Ahlrichs R (2005) Phys Chem Chem Phys 7:3297
- Peterson KA, Figgen D, Goll E, Stoll H, Dolg M (2003) J Chem Phys 119:11113
- Deglmann P, May K, Furche F, Ahlrichs R (2004) Chem Phys Lett 384:103
- Deglmann P, Furche F, Ahlrichs R (2001) Chem Phys Lett 362:511
- Deglmann P, Furche F (2002) J Chem Phys 117:9535
- Raghavachari K, Trucks GW (1989) Chem Phys Lett 157:479
- Dunning TH Jr (1989) J Chem Phys 90:1007
- Kendall R, Dunning TH Jr, Harrison RJ (1992) J Chem Phys 96:6796
- Woon DE, Dunning TH Jr (1993) J Chem Phys 98:1358
- Wilson AK, Woon DE, Peterson KA, Dunning TH Jr (1999) J Chem Phys 110:7667
- Werner H-J, Knowles PJ, Knizia G, Manby FR, Schütz M, Celani P, Korona T, Lindh R, Mitrushenkov A, Rauhut G, Shamasundar KR, Adler TB, Amos RD, Bernhardsson A, Berning A, Cooper DL, Deegan MJO, Dobbyn AJ, Eckert F, Goll E, Hampel C, Hesselmann A, Hetzer G, Hrenar T, Jensen G, Köppl C, Liu Y, Lloyd AW, Mata RA, May AJ, McNicholas SJ, Meyer W, Mura ME, Nicklass A, O'Neill DP, Palmieri P, Peng D, Pflüger K, Pitzer R, Reiher M, Shiozaki T, Stoll H, Stone AJ, Tarroni R, Thorsteinsson T, Wang M, MOLPRO, version 2012.1. a package of ab initio programs, <http://www.molpro.net>
- Reed AE, Weinstock RB, Weinhold F (1985) J Chem Phys 83:735
- Reed AE, Curtiss LA, Weinhold F (1988) Chem Rev 88:899
- Diedenhofen M, Wagoner T, Frenking G (2001) The accuracy of quantum chemical methods for the calculation of transition metal compounds. In: Cundari T (ed) Computational organometallic chemistry. Dekker, New York, pp 69–121
- Fernández I, Frenking G (2007) Chem Eur J 13:5873
- Fernández I, Frenking G (2006) Chem Eur J 12:3617
- Fernández I, Frenking G (2007) Faraday Discuss 135:403
- Ziegler T, Rauk A (1977) Theor Chim Acta 46:1
- ADF2012.01, SCM, Theoretical Chemistry, Vrije Universiteit, Amsterdam, <http://www.scm.com>
- Snijders JG, Vermooijs P, Baerends EJ (1981) At Data Nucl Data Tables 26:483
- Krijn J, Baerends EJ (1984) Internal Report: Fit Functions in the HFS Method. Vrije Universiteit, Amsterdam
- Chang C, Pelissier M, Durand P (1986) Phys Scr 34:394
- Heully J-L, Lindgren I, Lindroth E, Lundqvist S, Martensson-Pendrill A-M (1986) J Phys B 19:2799
- Snijders J (1996) Chem Phys Lett 252:51
- Lenthe EV, Baerends EJ, Snijders JG (1993) J Chem Phys 99:4597
- van Lenthe E, van Leeuwen R, Baerends EJ, Snijders JG (1996) Int J Quantum Chem 57:281
- Mitoraj MP, Michalak A, Ziegler T (2009) J Chem Theory Comput 5:962
- Frenking G, Wichmann K, Fröhlich N, Loschen C, Lein M, Frunzke J, Rayón VM (2003) Coord Chem Rev 55:238
- Lein M, Szabó A, Kovács A, Frenking G (2003) Faraday Discuss 124:365
- Lein M, Frenking G (2005) The nature of the chemical bond in the light of an energy decomposition analysis. In: Dykstra CE, Frenking G, Kim KS, Scuseria GE (eds) Theory, applications of computational chemistry: the first 40 years. Elsevier, Amsterdam, pp 291–372
- Frenking G (2001) J Organomet Chem 635:9

68. Cases M, Frenking G, Duran M, Solà M (2002) *Organometallics* 21:4182
69. Wiberg KB, Bailey WF, Petersson GA (2011) *J Phys Chem A* 115:12624
70. Himmel D, Krossing I, Schnepf A (2014) *Angew Chem Int Ed* 53:370
71. Frenking G (2014) *Angew Chem Int Ed* 53:6040
72. Kutzelnigg W (1984) *Angew Chem Int Ed Engl* 23:272
73. Esterhuysen C, Frenking G (2004) *Theoret Chem Acc* 111:381. Erratum (2005) 113:294
74. Jerabek P, Frenking G (2014) *Theoret Chem Acc* 133:1447
75. Duncan JL (1978) *Mol Phys* 28:1177
76. Beers Y, Klein GP, Kirchoff WH, Johnson DR (1972) *J Mol Spectrosc* 44:533
77. Brown RD, Godfrey PD, McNaughton D, Taylor PR (1986) *J Mol Spectrosc* 120:292